

SBS 1.1-Compliant Gas Gauge and Protection Enabled with Impedance Track™ with External Battery Heater Control and LCD Display

Check for Samples: bq34z653

FEATURES

- Next Generation Patented Impedance Track™
 Technology Accurately Measures Available
 Charge in Li-Ion and Li-Polymer Batteries
 - Better than 1% Error over the Lifetime of the Battery
- Supports the Smart Battery Specification SBS v1.1
- Flexible Configuration for 2-Series to 4-Series Li-lon and Li-Polymer Cells
- Battery Temperature Heater Control
- Powerful 8-Bit RISC CPU with Ultralow Power Modes
- Full Array of Programmable Protection Features
 - Voltage, Current, and Temperature
- Satisfies JEITA Guidelines
- Added Flexibility to Handle More Complex Charging Profiles
- Lifetime Data Logging
- Drives 3-, 4-, and 5-Segment LED or LCD Display for Battery-Pack Conditions
- Supports SHA-1 Authentication
- Complete Battery Protection and Gas Gauge Solution in One Package
- Available in a 44-Pin TSSOP (DBT) package

APPLICATIONS

- Notebook PCs
- Medical and Test Equipment
- Portable Instrumentation

DESCRIPTION

The bg34z653 SBS-compliant gas gauge and protection IC, incorporating patented Impedance Track™ technology, is a single IC solution designed for battery-pack or in-system installation. The bq34z653 measures and maintains an accurate record of available charge in Li-Ion or Li-Polymer batteries using its integrated high-performance analog peripherals. The bq34z653 monitors capacity change, battery impedance, open-circuit voltage, and other critical parameters of the battery pack, which reports the information to the system host controller over a serial-communication bus. Together with the integrated analog front-end (AFE) short-circuit and overload protection, the bq34z653 maximizes functionality and safety while minimizing external component count, cost, and size in smart battery circuits.

The implemented Impedance Track gas gauging technology continuously analyzes the battery impedance, resulting in superior gas-gauging accuracy. This enables remaining capacity to be calculated with discharge rate, temperature, and cell aging—all accounted for during each stage of every cycle with high accuracy.

Impedance Track is a trademark of Texas Instruments.



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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

Table 1. AVAILABLE OPTIONS

| т | PACKAGE ⁽¹⁾ | | | | |
|---------------|----------------------------|----------------------------------|--|--|--|
| IA | 44-PIN TSSOP (DBT) Tube | 44-PIN TSSOP (DBT) Tape and Reel | | | |
| -40°C to 85°C | bq34z653DBT ⁽²⁾ | bq34z653DBTR ⁽³⁾ | | | |

- (1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.
- (2) A single tube quantity is 40 units.
- (3) A single reel quantity is 2000 units.



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

THERMAL INFORMATION

| | | bq34z653 | |
|------------------------------|---|----------|-------|
| | THERMAL METRIC ⁽¹⁾ | TSSOP | UNITS |
| | | 44 PINS | |
| θ _{JA, High K} | Junction-to-ambient thermal resistance ⁽²⁾ | 60.9 | |
| $\theta_{JC(top)}$ | Junction-to-case(top) thermal resistance (3) | 15.3 | |
| θ_{JB} | Junction-to-board thermal resistance (4) | 30.2 | °C/W |
| ΨЈТ | Junction-to-top characterization parameter (5) | 0.3 | C/VV |
| ΨЈВ | Junction-to-board characterization parameter (6) | 27.2 | |
| $\theta_{\text{JC(bottom)}}$ | Junction-to-case(bottom) thermal resistance (7) | n/a | |

- (1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.
- (2) The junction-to-ambient thermal resistance under natural convection is obtained in a simulation on a JEDEC-standard, high-K board, as specified in JESD51-7, in an environment described in JESD51-2a.
- (3) The junction-to-case (top) thermal resistance is obtained by simulating a cold plate test on the package top. No specific JEDEC-standard test exists, but a close description can be found in the ANSI SEMI standard G30-88.
- (4) The junction-to-board thermal resistance is obtained by simulating in an environment with a ring cold plate fixture to control the PCB temperature, as described in JESD51-8.
- (5) The junction-to-top characterization parameter, ψ_{JT} , estimates the junction temperature of a device in a real system and is extracted from the simulation data for obtaining θ_{JA} , using a procedure described in JESD51-2a (sections 6 and 7).
- (6) The junction-to-board characterization parameter, ψ_{JB}, estimates the junction temperature of a device in a real system and is extracted from the simulation data for obtaining θ_{JA}, using a procedure described in JESD51-2a (sections 6 and 7).
- (7) The junction-to-case (bottom) thermal resistance is obtained by simulating a cold plate test on the exposed (power) pad. No specific JEDEC standard test exists, but a close description can be found in the ANSI SEMI standard G30-88.

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TYPICAL APPLICATION

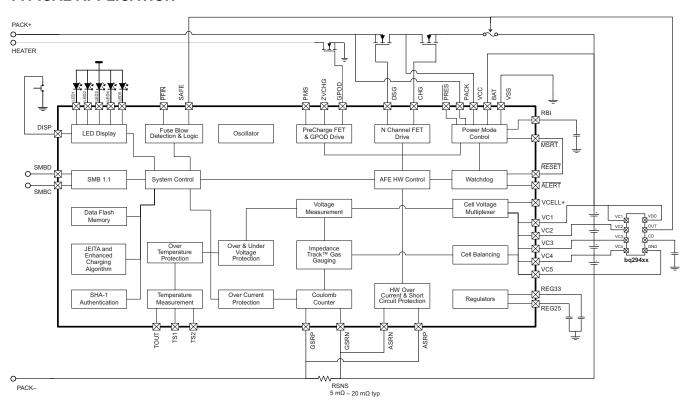


Figure 1. System Partitioning Diagram

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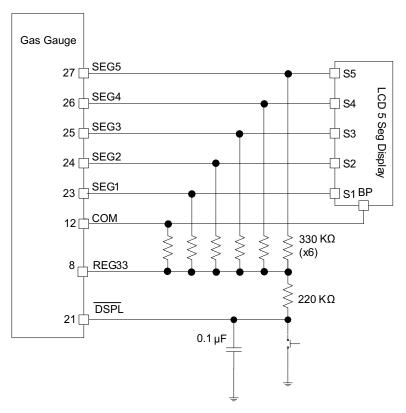
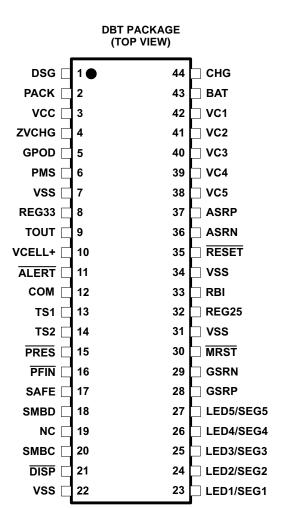


Figure 2. Typical LCD Implementation

PACKAGE PINOUT DIAGRAM



PIN FUNCTIONS

| | PIN | I/O ⁽¹⁾ | DECORIDATION |
|-----|--------|--------------------|---|
| NO. | NAME | 1/01.7 | DESCRIPTION |
| 1 | DSG | 0 | High-side N-channel discharge FET gate drive |
| 2 | PACK | IA, P | Battery pack input voltage sense input. It also serves as device wake up when device is in SHUTDOWN mode. |
| 3 | VCC | Р | Positive device supply input. Connect to the center connection of the CHG FET and DSG FET to ensure device supply either from battery stack or battery pack input. |
| 4 | ZVCHG | 0 | P-channel pre-charge FET gate drive |
| 5 | GPOD | OD | High voltage general purpose open drain output. It can be configured to be used in pre-charge condition. |
| 6 | PMS | I | PRE-CHARGE mode setting input. Connect to PACK to enable 0v pre-charge using charge FET connected at CHG pin. Connect to VSS to disable 0-V pre-charge using charge FET connected at CHG pin. |
| 7 | VSS | Р | Negative supply voltage input. Connect all VSS pins together for operation of device. |
| 8 | REG33 | Р | 3.3-V regulator output. Connect at least a 2.2-µF capacitor to REG33 and VSS. |
| 9 | TOUT | Р | Thermistor bias supply output |
| 10 | VCELL+ | _ | Internal cell voltage multiplexer and amplifier output. Connect a 0.1-µF capacitor to VCELL+ and VSS. |
| 11 | ALERT | I/OD | Alert output. In case of short circuit condition, overload condition and watchdog timeout, this pin will be triggered. |
| 12 | COM | 0 | Output/open drain: LCD common connection |

(1) I = Input, IA = Analog input, I/O = Input/output, I/OD = Input/Open-drain output, O = Output, OA = Analog output, P = Power



PIN FUNCTIONS (continued)

| | PIN | | , , |
|-----|-----------|--------------------|---|
| NO. | NAME | I/O ⁽¹⁾ | DESCRIPTION |
| 13 | TS1 | IA | 1st thermistor voltage input connection to monitor temperature |
| 14 | TS2 | IA | 2 nd thermistor voltage input connection to monitor temperature |
| 15 | PRES | 1 | Active low input to sense system insertion. Typically requires additional ESD protection. |
| 16 | PFIN | I | Active low input to detect secondary protector status, and to allow the bq34z653 to report the status of the 2 nd -level protection input |
| 17 | SAFE | 0 | Active high output to enforce additional level of safety protection; e.g., fuse blow |
| 18 | SMBD | I/OD | SMBus data open-drain bidirectional pin used to transfer address and data to and from the bq34z653 |
| 19 | NC | | Not used—leave floating. |
| 20 | SMBC | I/OD | SMBus clock open-drain bidirectional pin used to clock the data transfer to and from the bq34z653 |
| 21 | DISP | I/OD | Display control for the LEDs. This pin is typically connected to VCC via a 100-k Ω resistor and a push button switch connected to VSS. |
| 22 | VSS | Р | Negative supply voltage input. Connect all VSS pins together for operation of device. |
| 23 | LED1/SEG1 | I | LED1/SEG1 display segment that drives an external LED or LCD depending on the firmware configuration |
| 24 | LED2/SEG2 | I | LED2/SEG2 display segment that drives an external LED or LCD depending on the firmware configuration |
| 25 | LED3/SEG3 | I | LED3/SEG3 display segment that drives an external LED or LCD depending on the firmware configuration |
| 26 | LED4/SEG4 | I | LED4/SEG4 display segment that drives an external LED or LCD depending on the firmware configuration |
| 27 | LED5/SEG5 | I | LED5/SEG5 display segment that drives an external LED or LCD depending on the firmware configuration |
| 28 | GSRP | IA | Coulomb counter differential input. Connect to one side of the sense resistor. |
| 29 | GSRN | IA | Coulomb counter differential input. Connect to one side of the sense resistor. |
| 30 | MRST | 1 | Master reset input that forces the device into reset when held low. Must be held high for normal operation. Connect to RESET for correct operation of device. |
| 31 | VSS | Р | Negative supply voltage input. Connect all VSS pins together for operation of device. |
| 32 | REG25 | Р | 2.5-V regulator output. Connect at least a 1-mF capacitor to REG25 and VSS. |
| 33 | RBI | Р | RAM/Register backup input. Connect a capacitor to this pin and VSS to protect loss of RAM/Register data in case of short circuit condition. |
| 34 | VSS | Р | Negative supply voltage input. Connect all VSS pins together for operation of device. |
| 35 | RESET | 0 | Reset output. Connect to MSRT. |
| 36 | ASRN | IA | Short circuit and overload detection differential input. Connect to sense resistor. |
| 37 | ASRP | IA | Short circuit and overload detection differential input. Connect to sense resistor. |
| 38 | VC5 | IA, P | Cell voltage sense input and cell balancing input for the negative voltage of the bottom cell in cell stack. |
| 39 | VC4 | IA, P | Cell voltage sense input and cell balancing input for the positive voltage of the bottom cell and the negative voltage of the second lowest cell in cell stack. |
| 40 | VC3 | IA, P | Cell voltage sense input and cell balancing input for the positive voltage of the second lowest cell in cell stack and the negative voltage of the second highest cell in 4-series cell applications. |
| 41 | VC2 | IA, P | Cell voltage sense input and cell balancing input for the positive voltage of the second highest cell and the negative voltage of the highest cell in 4-series cell applications. Connect to VC3 in 2-series cell stack applications. |
| 42 | VC1 | IA, P | Cell voltage sense input and cell balancing input for the positive voltage of the highest cell in cell stack in 4-series cell applications. Connect to VC2 in 3-series or 2-series cell stack applications. |
| 43 | BAT | I, P | Battery stack voltage sense input |
| 44 | CHG | 0 | High-side N-channel charge FET gate drive |

ABSOLUTE MAXIMUM RATINGS

Over operating free-air temperature (unless otherwise noted) (1)

| | | PIN | UNIT |
|------------------|--|--|--|
| | | BAT, VCC | –0.3 V to 34 V |
| | | PACK, PMS | –0.3 V to 34 V |
| V_{SS} | Supply voltage range | VC(n) – VC(n+1); n = 1, 2, 3, 4 | –0.3 V to 8.5 V |
| | | VC1, VC2, VC3, VC4 | –0.3 V to 34 V |
| | | VC5 | –0.3 V to 1 V |
| | | PFIN, SMBD, SMBC. LED1, LED2, LED3, LED4, LED5, DISP | –0.3 V to 6 V |
| V _{IN} | Input voltage range | TS1, TS2, SAFE, VCELL+, PRES, ALERT | -0.3 V to V _(REG25) + 0.3 V |
| | | MRST, GSRN, GSRP, RBI | -0.3 V to V _(REG25) + 0.3 V |
| | | ASRN, ASRP | –1 V to 1 V |
| | | DSG, CHG, GPOD | –0.3 V to 34 V |
| | | ZVCHG | $-0.3 \text{ V to V}_{(BAT)}$ |
| V_{OUT} | Output voltage range | TOUT, ALERT, REG33 | –0.3 V to 6 V |
| | | RESET | –0.3 V to 7 V |
| | | REG25 | –0.3 V to 2.75 V |
| I _{SS} | Maximum combined sink current for input pins | PRES, PFIN, SMBD, SMBC, LED1, LED2, LED3, LED4, LED5 | 50 mA |
| T _A | Operating free-air temperature range | | –40°C to 85°C |
| T _F | Functional temperature | | –40°C to 100°C |
| T _{stg} | Storage temperature range | | –65°C to 150°C |

⁽¹⁾ Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

RECOMMENDED OPERATING CONDITIONS

Over operating free-air temperature range (unless otherwise noted)

| | | PIN | MIN | NOM | MAX | UNIT |
|------------------------|--|------------------------------|------|-----|------------------|------|
| V_{SS} | Supply voltage | VCC, BAT | 4.5 | • | 25 | ٧ |
| V _(STARTUP) | Minimum startup voltage | VCC, BAT, PACK | 5.5 | | | ٧ |
| | | VC(n) - VC(n+1); n = 1,2,3,4 | 0 | | 5 | ٧ |
| | | VC1, VC2, VC3, VC4 | 0 | | V_{SUP} | ٧ |
| V_{IN} | Input Voltage Range | VC5 | 0 | | 0.5 | ٧ |
| | | ASRN, ASRP | -0.5 | | 0.5 | ٧ |
| | | PACK, PMS | 0 | | 25 | V |
| V _(GPOD) | Output Voltage Range | GPOD | 0 | | 25 | V |
| A _(GPOD) | Drain Current ⁽¹⁾ | GPOD | | | 1 | mA |
| C _(REG25) | 2.5-V LDO Capacitor | REG25 | 1 | | | μF |
| C _(REG33) | 3.3-V LDO Capacitor | REG33 | 2.2 | | | μF |
| C _(VCELL+) | Cell Voltage Output Capacitor | VCELL+ | 0.1 | | | μF |
| C _(PACK) | PACK input block resistor ⁽²⁾ | PACK | 1 | | | kΩ |

⁽¹⁾ Use an external resistor to limit the current to GPOD to 1 mA in high voltage application.

⁽²⁾ Use an external resistor to limit the in-rush current PACK pin required.



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ELECTRICAL CHARACTERISTICS

Over operating free-air temperature range (unless otherwise noted), $T_A = -40^{\circ}\text{C}$ to 85°C, $V_{(REG25)} = 2.41 \text{ V}$ to 2.59 V, $V_{(BAT)} = 14 \text{ V}$, $C_{(REG25)} = 1 \text{ }\mu\text{F}$, $C_{(REG33)} = 2.2 \text{ }\mu\text{F}$; typical values at $T_A = 25^{\circ}\text{C}$ (unless otherwise noted)

| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|-----------------------------|---|--|------|---------------|-----------|------|
| SUPPLY CUR | RENT | | | | | |
| (NORMAL) | Firmware running | | | 550 | | μA |
| (SLEEP) | SLEEP mode | CHG FET on; DSG FET on | | 124 | | μA |
| | | CHG FET off; DSG FET on | | 90 | | μA |
| | | CHG FET off; DSG FET off | | 52 | | μΑ |
| (SHUTDOWN) | SHUTDOWN mode | | | 0.1 | 1 | μA |
| SHUTDOWN V | NAKE; T _A = 25°C (unless otherwise no | oted) | | | | |
| I _(PACK) | SHUTDOWN exit at V _{STARTUP} threshold | | | | 1 | μA |
| 3Rx WAKE FF | ROM SLEEP; $T_A = 25^{\circ}C$ (unless otherw | rise noted) | | | | |
| V _(WAKE) | Positive or negative wake threshold with 1.00 mV, 2.25 mV, 4.5 mV and 9 mV programmable options | | 1.25 | | 10 | mV |
| | | V _(WAKE) = 1 mV; I _(WAKE) = 0, RSNS1 = 0, RSNS0 = 1; | -0.7 | | 0.7 | |
| V | Accuracy of V _(WAKF) | $\begin{split} &V_{(WAKE)} = 2.25 \text{ mV}; \\ &I_{(WAKE)} = 1, \text{ RSNS1} = 0, \text{ RSNS0} = 1; \\ &I_{(WAKE)} = 0, \text{ RSNS1} = 1, \text{ RSNS0} = 0; \end{split}$ | -0.8 | | 0.8 | — mV |
| V _(WAKE_ACR) | Accuracy of V _(WAKE) | $\begin{split} &V_{(WAKE)} = 4.5 \text{ mV}; \\ &I_{(WAKE)} = 1, \text{ RSNS1} = 1, \text{ RSNS0} = 1; \\ &I_{(WAKE)} = 0, \text{ RSNS1} = 1, \text{ RSNS0} = 0; \end{split}$ | -1.0 | | 1.0 | |
| | | V _(WAKE) = 9 mV; I _(WAKE) = 1, RSNS1 = 1, RSNS0 = 1; | -1.4 | | 1.4 | |
| V _(WAKE_TCO) | Temperature drift of $V_{(WAKE)}$ accuracy | | | 0.5 | | %/°C |
| t _(WAKE) | Time from application of current and wake of bq34z653 | | | 1 | 10 | ms |
| WATCHDOG 1 | TIMER | | | | | |
| WDTINT | Watchdog start up detect time | | 250 | 500 | 1000 | ms |
| t _{WDWT} | Watchdog detect time | | 50 | 100 | 150 | μs |
| 2.5-V LDO; I _(R) | $_{EG33OUT)} = 0 \text{ mA}; T_A = 25^{\circ}\text{C} \text{ (unless oth)}$ | erwise noted) | | | | |
| V _(REG25) | Regulator output voltage | 4.5 < VCC or BAT < 25 V; I _(REG250UT) ≤ 16 mA; T _A = -40°C to 100°C | 2.41 | 2.5 | 2.59 | V |
| ΔV _(REG25TEMP) | Regulator output change with temperature | I _(REG25OUT) = 2 mA; T _A = -40°C to 100°C | | ±0.2 | | % |
| ΔV _(REG25LINE) | Line regulation | 5.4 < VCC or BAT < 25 V; I _(REG25OUT) = 2 mA | | 3 | 10 | mV |
| ۸\/ | Load Regulation | $0.2 \text{ mA} \le I_{(REG25OUT)} \le 2 \text{ mA}$ | | 7 | 25 | mV |
| ∆V _(REG25LOAD) | Load Regulation | 0.2 mA ≤ I _(REG25OUT) ≤ 16 mA | | 25 | 50 | IIIV |
| (REG25MAX) | Current Limit | Drawing current until REG25 = 2 V to 0 V | 5 | 40 | 75 | mA |
| 3.3-V LDO; I _{(R} | EG25OUT) = 0 mA; T _A = 25°C (unless oth | erwise noted) | | | | |
| V _(REG33) | Regulator output voltage | 4.5 < VCC or BAT < 25 V; I _(REG330UT) ≤ 25 mA; T _A = -40°C to 100°C | 3 | 3.3 | 3.6 | ٧ |
| ΔV _(REG33TEMP) | Regulator output change with temperature | I _(REG33OUT) = 2 mA; T _A = -40°C to 100°C | | ±0.2 | | % |
| ΔV _(REG33LINE) | Line regulation | 5.4 < VCC or BAT < 25 V; I _(REG33OUT) = 2 mA | | 3 | 10 | mV |
| ΔV _(REG33LOAD) | Load Regulation | 0.2 mA ≤ I _(REG33OUT) ≤ 2 mA 0.2 mA ≤ I _(REG33OUT) ≤ 25 mA | | 7 40 | 17 100 | mV |
| | | Drawing current until REG33 = 3 V | 25 | 100 | 145 | |
| (REG33MAX) | Current Limit | Short REG33 to VSS, REG33 = 0 V | 12 | | 65 | mA |
| THERMISTOR | DRIVE | | | | | |
| √ _(TOUT) | Output voltage | $I_{(TOUT)} = 0 \text{ mA}; T_A = 25^{\circ}\text{C}$ | | $V_{(REG25)}$ | | V |

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ELECTRICAL CHARACTERISTICS (continued)

Over operating free-air temperature range (unless otherwise noted), $T_A = -40^{\circ}\text{C}$ to 85°C, $V_{(REG25)} = 2.41 \text{ V}$ to 2.59 V, $V_{(RAT)} = 14 \text{ V}$. $C_{(REG25)} = 1 \text{ µF}$. $C_{(REG23)} = 2.2 \text{ µF}$: typical values at $T_A = 25^{\circ}\text{C}$ (unless otherwise noted)

| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|---------------------------|---|--|-----------------------------------|-------------------------|-----------------------------------|------|
| R _{DS(on)} | TOUT pass element resistance | I _(TOUT) = 1 mA; R _{DS(on)} = (V _(REG25) – V _(TOUT))/ 1 mA; T _A = -40°C to 100°C | | 50 | 100 | Ω |
| LED OR LCD | OUTPUTS | | | | | |
| V _{OL} | Output low voltage | LED1, LED2, LED3, LED4, LED5 | | | 0.4 | V |
| VCELL+ HIGH | VOLTAGE TRANSLATION | | | | | |
| M | Translation output | VC(n) - VC(n+1) = 0 V; $T_A = -40^{\circ}C \text{ to } 100^{\circ}C$ | 0.950 | 0.975 | 1 | |
| V _(VCELL+OUT) | | VC(n) - VC(n+1) = 4.5 V; $T_A = -40^{\circ}C$ to 100°C | 0.275 | 0.3 | 0.375 | |
| V _(VCELL+REF) | | Internal AFE reference voltage; T _A = -40°C to 100°C | 0.965 | 0.975 | 0.985 | V |
| V _(VCELL+PACK) | | Voltage at PACK pin; T _A = -40°C to 100°C | 0.98 × V _(PACK) /18 | V _(PACK) /18 | 1.02 × V _(PACK) /18 | |
| V _(VCELL+BAT) | | Voltage at BAT pin; T _A = -40°C to 100°C | 0.98 × V _(BAT) /18 | V _(BAT) /18 | 1.02 × V _(BAT) /18 | |
| CMMR | Common mode rejection ratio | VCELL+ | 40 | | | dB |
| K | Cell scale factor | K= {VCELL+ output (VC5=0 V; VC4=4.5 V) – VCELL+ output (VC5 = 0 V; VC4 =0 V)}/4.5 | 0.147 | 0.150 | 0.153 | |
| | Gen scale ractor | K= {VCELL+ output (VC2 = 13.5 V; VC1 = 18 V) – VCELL+ output (VC5 = 13.5 V; VC1 = 13.5 V)}/4.5 | 0.147 | 0.150 | 0.153 | |
| I _(VCELL+OUT) | Drive Current to VCELL+ capacitor | $VC(n) - VC(n+1) = 0 V$; $VCELL+ = 0 V$; $T_A = -40^{\circ}C$ to $100^{\circ}C$ | 12 | 18 | | μΑ |
| V _(VCELL+O) | CELL offset error | CELL output (VC2 = VC1 = 18 V) – CELL output (VC2 = VC1 = 0 V) | -18 | -1 | 18 | mV |
| VCnL | VC(n) pin leakage current | VC1, VC2, VC3, VC4, VC5 = 3 V | -1 | 0.01 | 1 | μΑ |
| CELL BALAN | CING | | | | | |
| R _{BAL} | Internal cell balancing FET resistance | $R_{DS(on)}$ for internal FET switch at $V_{DS} = 2 \text{ V}$; $T_A = 25^{\circ}\text{C}$ | 200 | 400 | 600 | Ω |
| HARDWARE | SHORT CIRCUIT AND OVERLOAD PR | OTECTION; T _A = 25°C (unless otherwise n | oted) | | | |
| | | V _{OL} = 25 mV (min) | 15 | 25 | 35 | |
| $I_{(OL)}$ | OL detection threshold voltage accuracy | V _{OL} = 100 mV; RSNS = 0, 1 | 90 | 100 | 110 | mV |
| | 4004.40, | V _{OL} = 205 mV (max) | 185 | 205 | 225 | |
| | | V _(SCC) = 50 mV (min) | 30 | 50 | 70 | |
| V _(SCC) | SCC detection threshold voltage accuracy | V _(SCC) = 200 mV; RSNS = 0, 1 | 180 | 200 | 220 | mV |
| | accuracy | V _(SCC) = 475 mV (max) | 428 | 475 | 523 | |
| | | V _(SCD) = -50 mV (min) | -30 | -50 | -70 | |
| / _(SCD) | SCD detection threshold voltage | V _(SCD) = -200 mV; RSNS = 0, 1 | -180 | -200 | -220 | mV |
| | accuracy | V _(SCD) = -475 mV (max) | -428 | –475 | -523 | |
| da | Delay time accuracy | | | ±15.25 | | μs |
| pd | Protection circuit propagation delay | | | 50 | | μs |
| | IRCUIT; T _A = 25°C (unless otherwise n | oted) | | | | |
| / _(DSGON) | DSG pin output on voltage | $\begin{array}{c} V_{(DSGON)} = V_{(DSG)} - V_{(PACK)}; \\ V_{(GS)} = 10~M\Omega;~DSG~and~CHG~on; \\ T_A = -40^{\circ}C~to~100^{\circ}C \end{array}$ | 8 | 12 | 16 | V |
| V _(CHGON) | CHG pin output on voltage | $\begin{array}{c} V_{(CHGON)} = V_{(CHG)} - V_{(BAT)}; \\ V_{(CS)} = 10~M\Omega;~DSG~and~CHG~on; \\ T_A = -40^{\circ}C~to~100^{\circ}C \end{array}$ | 8 | 12 | 16 | ٧ |
| / _(DSGOFF) | DSG pin output off voltage | $V_{(DSGOFF)} = V_{(DSG)} - V_{(PACK)}$ | | | 0.2 | V |
| V _(CHGOFF) | CHG pin output off voltage | $V_{(CHGOFF)} = V_{(CHG)} - V_{(BAT)}$ | | | 0.2 | V |
| t _r | Rise time | C_L = 4700 pF; $V_{(PACK)} \le DSG \le V_{(PACK)} + 4 V$ | | 400 | 1000 | μs |
| | | C _L = 4700 pF; V _(BAT) ≤ CHG ≤ V _(BAT) + 4 V | | 400 | 1000 | ۳- |



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ELECTRICAL CHARACTERISTICS (continued)

Over operating free-air temperature range (unless otherwise noted), $T_A = -40^{\circ}\text{C}$ to 85°C, $V_{(REG25)} = 2.41 \text{ V}$ to 2.59 V, $V_{(BAT)} = 14 \text{ V}$, $C_{(REG25)} = 1 \text{ }\mu\text{F}$, $C_{(REG33)} = 2.2 \text{ }\mu\text{F}$; typical values at $T_A = 25^{\circ}\text{C}$ (unless otherwise noted)

| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|------------------------|---|--|--------------------------|--------|--------|---------------------|
| | E.H.C. | C_L = 4700 pF; $V_{(PACK)}$ + $V_{(DSGON)}$ \leq DSG \leq $V_{(PACK)}$ + 1 V | | 40 | 200 | |
| t _f | Fall time | C _L = 4700 pF; V _(BAT) + V _(CHGON) ≤ CHG ≤ V _(BAT) + 1 V | | 40 | 200 | μs |
| V _(ZVCHG) | ZVCHG clamp voltage | BAT = 4.5 V | 3.3 | 3.5 | 3.7 | V |
| LOGIC; TA : | = -40°C to 100°C (unless otherwise n | oted) | | | | |
| _ | | ALERT | 60 | 100 | 200 | |
| R _(PULLUP) | Internal pullup resistance | RESET | 1 | 3 | 6 | kΩ |
| | | ALERT | | | 0.2 | |
| V_{OL} | Logic low output voltage level | $\overline{\text{RESET}}$; V _(BAT) = 7 V; V _(REG25) = 1.5 V; I $\overline{\text{(RESET)}}$ = 200 μA | | | 0.4 | V |
| | | GPOD; $I_{(GPOD)} = 50 \mu A$ | | | 0.6 | |
| LOGIC SME | BC, SMBD, <u>PFIN, PRES,</u> SAFE, ALERT | r, DISP , COM | | | | |
| V _{IH} | High-level input voltage | | 2.0 | | | V |
| V _{IL} | Low-level input voltage | | | | 0.8 | V |
| V _{OH} | Output voltage high ⁽¹⁾ | I _L = -0.5 mA | V _{REG25} - 0.5 | | | V |
| V _{OL} | Low-level output voltage | PRES, PFIN, ALERT, DISP; I _L = 7 mA; | | | 0.4 | V |
| Cı | Input capacitance | | | 5 | | pF |
| I _(SAFE) | SAFE source currents | SAFE active, SAFE = V _(REG25) – 0.6 V | -3 | | | mA |
| I _{lkg(SAFE)} | SAFE leakage current | SAFE inactive | -0.2 | | 0.2 | μA |
| I _{lkg} | Input leakage current | | | | 1 | μA |
| ADC ⁽²⁾ | | | | | | ' |
| | Input voltage range | TS1, TS2, using Internal V _{ref} | -0.2 | | 1 | V |
| | Conversion time | | | 31.5 | | ms |
| | Resolution (no missing codes) | | 16 | | | bits |
| | Effective resolution | | 14 | 15 | | bits |
| | Integral nonlinearity | | | | ±0.03 | %FSR ⁽³⁾ |
| | Offset error ⁽⁴⁾ | | | 140 | 250 | μV |
| | Offset error drift ⁽⁴⁾ | T _A = 25°C to 85°C | | 2.5 | 18 | μV/°C |
| | Full-scale error ⁽⁵⁾ | | | ±0.1% | ±0.7% | |
| | Full-scale error drift | | | 50 | | PPM/°C |
| | Effective input resistance ⁽⁶⁾ | | 8 | | | МΩ |
| COULOMB | | | | | | |
| | Input voltage range | | -0.20 | | 0.20 | V |
| | Conversion time | Single conversion | | 250 | | ms |
| | Effective resolution | Single conversion | 15 | | | bits |
| | | -0.1 V to 0.20 V | | ±0.007 | ±0.034 | |
| | Integral nonlinearity | -0.20 V to −0.1 V | | ±0.007 | | %FSR |
| | Offset error (7) | T _A = 25°C to 85°C | | 10 | | μV |
| | Offset error drift | | | 0.4 | 0.7 | μV/°C |
| | Full-scale error ⁽⁸⁾ (9) | | | ±0.35% | | · · |
| | Full-scale error drift | | | 150 | | PPM/°C |

- (1) RC[0:7] bus
- (2) Unless otherwise specified, the specification limits are valid at all measurement speed modes.
- (3) Full-scale reference
- (4) Post-calibration performance and no I/O changes during conversion with SRN as the ground reference
- (5) Uncalibrated performance. This gain error can be eliminated with external calibration.
- (6) The A/D input is a switched-capacitor input. Since the input is switched, the effective input resistance is a measure of the average resistance.

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- (7) Post-calibration performance
- (8) Reference voltage for the coulomb counter is typically $V_{ref}/3.969$ at $V_{(REG25)} = 2.5$ V, $T_A = 25$ °C.
- (9) Uncalibrated performance. This gain error can be eliminated with external calibration.

ELECTRICAL CHARACTERISTICS (continued)

Over operating free-air temperature range (unless otherwise noted), $T_A = -40^{\circ}\text{C}$ to 85°C, $V_{(REG25)} = 2.41 \text{ V}$ to 2.59 V, $V_{(BAT)} = 14 \text{ V}$, $C_{(REG25)} = 1 \text{ }\mu\text{F}$, $C_{(REG33)} = 2.2 \text{ }\mu\text{F}$; typical values at $T_A = 25^{\circ}\text{C}$ (unless otherwise noted)

| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|---------------------|--|-------------------------------|-------|--------|-------|--------|
| | Effective input resistance ⁽¹⁰⁾ | T _A = 25°C to 85°C | 2.5 | | | ΜΩ |
| INTERNAL | TEMPERATURE SENSOR | | | | | |
| V _(TEMP) | Temperature sensor voltage ⁽¹¹⁾ | | | -2.0 | | mV/°C |
| VOLTAGE | REFERENCE | • | | | | |
| | Output voltage | | 1.215 | 1.225 | 1.230 | V |
| | Output voltage drift | | | 65 | | PPM/°C |
| HIGH FRE | QUENCY OSCILLATOR | | | | | |
| f _(OSC) | Operating frequency | | | 4.194 | | MHz |
| £ | Frequency error (12) (13) | | -3% | 0.25% | 3% | |
| f _(EIO) | Frequency error (1974) | T _A = 20°C to 70°C | -2% | 0.25% | 2% | |
| t _(SXO) | Start-up time ⁽¹⁴⁾ | | | 2.5 | 5 | ms |
| LOW FRE | QUENCY OSCILLATOR | | | | | |
| f _(LOSC) | Operating frequency | | | 32.768 | | kHz |
| £ | C(13) (15) | | -2.5% | 0.25% | 2.5% | |
| f _(LEIO) | Frequency error ⁽¹³⁾ (15) | T _A = 20°C to 70°C | -1.5% | 0.25% | 1.5% | |
| t _(LSXO) | Start-up time ⁽¹⁴⁾ | | | | 500 | μs |

⁽¹⁰⁾ The CC input is a switched capacitor input. Since the input is switched, the effective input resistance is a measure of the average resistance.

POWER-ON RESET

Over operating free-air temperature range (unless otherwise noted), $T_A = -40^{\circ}\text{C}$ to 85°C, $V_{(REG25)} = 2.41 \text{ V}$ to 2.59 V, $V_{(BAT)} = 14 \text{ V}$, $C_{(REG25)} = 1 \text{ }\mu\text{F}$, $C_{(REG33)} = 2.2 \text{ }\mu\text{F}$; typical values at $T_A = 25^{\circ}\text{C}$ (unless otherwise noted)

| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|------------------|------------------------------|--|-----|-----|-----|------|
| VIT- | Negative-going voltage input | | 1.7 | 1.8 | 1.9 | V |
| VHYS | Power-on reset hysteresis | | 5 | 125 | 200 | mV |
| t _{RST} | RESET active low time | Active low time after power up or watchdog reset | 100 | 250 | 560 | μs |

^{(11) -53.7} LSB/°C

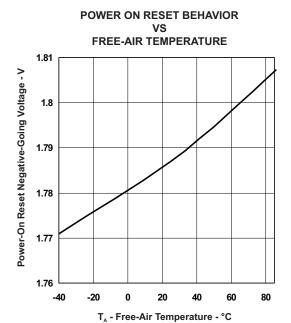
⁽¹²⁾ The frequency error is measured from 4.194 MHz.

⁽¹³⁾ The frequency drift is included and measured from the trimmed frequency at V_(REG25) = 2.5 V, T_A = 25°C.

⁽¹⁴⁾ The startup time is defined as the time it takes for the oscillator output frequency to be $\pm 3\%$.

⁽¹⁵⁾ The frequency error is measured from 32.768 kHz.





DATA FLASH CHARACTERISTICS OVER RECOMMENDED OPERATING TEMPERATURE AND SUPPLY VOLTAGE

Typical values at $T_A = 25$ °C and $V_{(REG25)} = 2.5$ V (unless otherwise noted)

| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|--------------------------|--|--|-----|------|------|--------|
| | Data retention | | 10 | | | Years |
| | Flash programming write-cycles | | 20k | | | Cycles |
| t _(ROWPROG) | Row programming time | See (1) | | | 2 | ms |
| t _(MASSERASE) | Mass-erase time | | | | 200 | ms |
| t _(PAGEERASE) | Page-erase time | | | | 20 | ms |
| I _(DDPROG) | Flash-write supply current | | | 5 | 10 | mA |
| I _(DDERASE) | Flash-erase supply current | | | 5 | 10 | mA |
| RAM/REGIS | TER BACKUP | | | | | |
| | RB data-retention input current | $V_{(RBI)} > V_{(RBI)MIN}$, $V_{REG25} < V_{IT-}$, $T_A = 85$ °C | | 1000 | 2500 | nA |
| I _(RB) | RB data-retention input current | $V_{(RBI)} > V_{(RBI)MIN}$, $V_{REG25} < V_{IT-}$, $T_A = 25$ °C | | 90 | 220 | IIA |
| V _(RB) | RB data-retention input voltage ⁽²⁾ | | 1.7 | | | V |

Specified by design. Not production tested. Specified by design. Not production tested.

SMBus TIMING CHARACTERISTICS

 $T_A = -40$ °C to 85°C Typical Values at $T_A = 25$ °C and $V_{REG25} = 2.5$ V (Unless Otherwise Noted)

| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|-----------------------|--|--|-----|------|-----|------|
| f _(SMB) | SMBus operating frequency | SLAVE mode, SMBC 50% duty cycle | 10 | | 100 | kHz |
| f _(MAS) | SMBus master clock frequency | MASTER mode, No clock low slave extend | | 51.2 | | kHz |
| t _(BUF) | Bus free time between start and stop (See Figure 3.) | | 4.7 | | | μs |
| t _(HD:STA) | Hold time after (repeated) start (See Figure 3.) | | 4 | | | μs |
| t _(SU:STA) | Repeated start setup time (See Figure 3.) | | 4.7 | | | μs |
| t _(SU:STO) | Stop setup time (See Figure 3.) | | 4 | | | μs |
| t _(HD:DAT) | Data hald time (Can Figure 2) | RECEIVE mode | 0 | | | ns |
| | Data hold time (See Figure 3.) | TRANSMIT mode | 300 | | | |

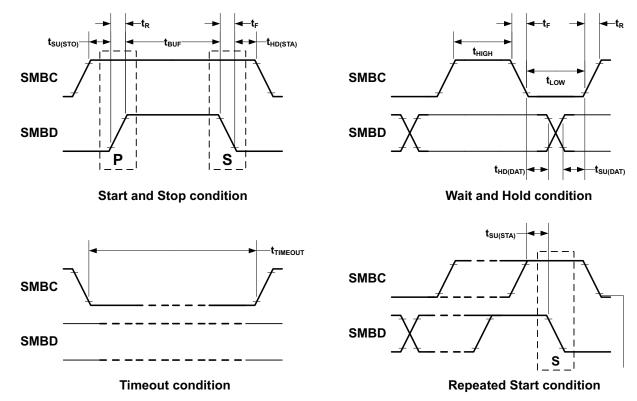
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SMBus TIMING CHARACTERISTICS (continued)

 $T_A = -40$ °C to 85°C Typical Values at $T_A = 25$ °C and $V_{REG25} = 2.5$ V (Unless Otherwise Noted)

| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|-------------------------|---|--------------------|-----|-----|------|------|
| t _(SU:DAT) | Data setup time (See Figure 3.) | | 250 | | | ns |
| t _(TIMEOUT) | Error signal/detect (See Figure 3.) | See ⁽¹⁾ | 25 | | 35 | μs |
| t _(LOW) | Clock low period (See Figure 3.) | | 4.7 | | | μs |
| t _(HIGH) | Clock high period (See Figure 3.) | See (2) | 4 | | 50 | μs |
| t _(LOW:SEXT) | Cumulative clock low slave extend time | See (3) | | | 25 | ms |
| t _(LOW:MEXT) | Cumulative clock low master extend time (See Figure 3.) | See (4) | | | 10 | ms |
| t _f | Clock/data fall time | See ⁽⁵⁾ | | | 300 | ns |
| t _r | Clock/data rise time | See (6) | | | 1000 | ns |

- The bq34z653 times out when any clock low exceeds $t_{(TIMEOUT)}$. $t_{(HIGH)}$. Max, is the minimum bus idle time. SMBC = SMBD = 1 for t > 50 ms causes reset of any transaction involving bq34z653 that is in progress. This specification is valid when the NC_SMB control bit remains in the default cleared state (CLK[0]=0).
- $t_{(LOW:SEXT)}$ is the cumulative time a slave device is allowed to extend the clock cycles in one message from initial start to the stop.
- t_(LOW:MEXT) is the cumulative time a master device is allowed to extend the clock cycles in one message from initial start to the stop. (4)
- Rise time $t_r = VILMAX 0.15$) to (VIHMIN + 0.15) (5)
- Fall time $t_f = 0.9V_{DD}$ to (VILMAX 0.15)



SCLKACK is the acknowledge-related clock pulse generated by the master.

Figure 3. SMBus Timing Diagram

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FEATURE SET

Primary (1st Level) Safety Features

The bq34z653 supports a wide range of battery and system protection features that can be easily configured. The primary safety features include:

- Cell over/undervoltage protection
- · Charge and discharge overcurrent
- Short circuit protection
- Charge and discharge overtemperature with independent alarms and thresholds for each thermistor
- AFE Watchdog

Secondary (2nd Level) Safety Features

The secondary safety features of the bq34z653 can be used to indicate more serious faults via the SAFE pin. This pin can be used to blow an in-line fuse to permanently disable the battery pack from charging or discharging. The secondary safety protection features include:

- · Safety overvoltage
- · Safety undervoltage
- · 2nd-level protection IC input
- Safety overcurrent in charge and discharge
- Safety over-temperature in charge and discharge with independent alarms and thresholds for each thermistor
- Charge FET and zero-volt charge FET fault
- · Discharge FET fault
- · Cell imbalance detection (active and at rest)
- Open thermistor detection
- · Fuse blow detection
- AFE communication fault

Charge Control Features

The bq34z653 charge control features include:

- Supports JEITA temperature ranges. Reports charging voltage and charging current according to the active temperature range
- Handles more complex charging profiles. Allows for splitting the standard temperature range into two subranges, and for varying the charging current according to the cell voltage
- Reports the appropriate charging current needed for constant current charging and the appropriate charging voltage needed for constant voltage charging to a smart charger using SMBus broadcasts
- Determines the chemical state of charge of each battery cell using Impedance Track, and can reduce the charge difference of the battery cells in a fully charged state of the battery pack, gradually using the cell balancing algorithm during charging. This prevents fully charged cells from overcharging and causing excessive degradation and also increases the usable pack energy by preventing premature charge termination.
- · Supports pre-charging/zero-volt charging
- Supports charge inhibit and charge suspend if battery pack temperature is out of temperature range
- Reports charging fault and also indicate charge status via charge and discharge alarms
- Battery heater control to allow battery charging in low ambient temperatures

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Gas Gauging

The bq34z653 uses the Impedance Track Technology to measure and calculate the available charge in battery cells. The achievable accuracy is better than 1% error over the lifetime of the battery and there is no full charge discharge learning cycle required.

See Theory and Implementation of Impedance Track Battery Fuel-Gauging Algorithm application note (SLUA364) for further details.

Lifetime Data Logging Features

The bq34z653 offers lifetime data logging, where important measurements are stored for warranty and analysis purposes. The data monitored include:

- Lifetime maximum temperature
- Lifetime maximum temperature count
- Lifetime maximum temperature duration
- · Lifetime minimum temperature
- · Lifetime maximum battery cell voltage
- · Lifetime maximum battery cell voltage count
- Lifetime maximum battery cell voltage duration
- · Lifetime minimum battery cell voltage
- · Lifetime maximum battery pack voltage
- · Lifetime minimum battery pack voltage
- · Lifetime maximum charge current
- Lifetime maximum discharge current
- Lifetime maximum charge power
- · Lifetime maximum discharge power
- Lifetime maximum average discharge current
- Lifetime maximum average discharge power
- · Lifetime average temperature

Authentication

The bq34z653 supports authentication by the host using SHA-1.

Power Modes

The bq34z653 supports three different power modes to reduce power consumption:

- In NORMAL mode, the bq34z653 performs measurements, calculations, protection decisions and data updates in 1-second intervals. Between these intervals, the bq34z653 is in a reduced power stage.
- In SLEEP mode, the bq34z653 performs measurements, calculations, protection decisions, and data updates
 in adjustable time intervals. Between these intervals, the bq34z653 is in a reduced power stage. The
 bq34z653 has a wake function that enables exit from SLEEP mode when current flow or failure is detected.
- In SHUTDOWN mode, the bg34z653 is completely disabled.



CONFIGURATION

Oscillator Function

The bg34z653 fully integrates the system oscillators; therefore, no external components are required for this feature.

System Present Operation

The bg34z653 periodically verifies the PRES pin and detects that the battery is present in the system via a low state on a PRES input. When this occurs, the bg34z653 enters NORMAL operating mode. When the pack is removed from the system and the PRES input is high, the bq34z653 enters the battery-removed state, disabling the charge, discharge, and ZVCHG FETs. The PRES input is ignored and can be left floating when non-removal mode is set in the data flash.

BATTERY PARAMETER MEASUREMENTS

The bq34z653 uses an integrating delta-sigma analog-to-digital converter (ADC) for current measurement, and a second delta-sigma ADC for individual cell and battery voltage and temperature measurement.

Charge and Discharge Counting

The integrating delta-sigma ADC measures the charge/discharge flow of the battery by measuring the voltage drop across a small-value sense resistor between the SR1 and SR2 pins. The integrating ADC measures bipolar signals from -0.25 V to 0.25 V. The bq34z653 detects charge activity when $V_{SR} = V_{(SRP)} - V_{(SRN)}$ is positive, and discharge activity when $V_{SR} = V_{(SRP)} - V_{(SRN)}$ is negative. The bq34z653 continuously integrates the signal over time using an internal counter. The fundamental rate of the counter is 0.65 nVh.

Voltage

The bq34z653 updates the individual series cell voltages at one second intervals. The internal ADC of the bg34z653 measures the voltage, and scales and calibrates it appropriately. This data is also used to calculate the impedance of the cell for the Impedance Track gas-gauging.

Current

The bg34z653 uses the SRP and SRN inputs to measure and calculate the battery charge and discharge current using a 5-m Ω to 20-m Ω typ. sense resistor.

Wake Function

The bg34z653 can exit SLEEP mode, if enabled, by the presence of a programmable level of current signal across SRP and SRN.

Auto Calibration

The bg34z653 provides an auto-calibration feature to cancel the voltage offset error across SRN and SRP for maximum charge measurement accuracy. The bg34z653 performs auto-calibration when the SMBus lines stay low continuously for a minimum of a programmable amount of time.

Temperature

The bg34z653 has an internal temperature sensor and two external temperature sensor inputs, TS1 and TS2. used in conjunction with two identical NTC thermistors (default is Semitec 103AT) to sense the battery environmental temperature. The bq34z653 can be configured to use the internal temperature sensor or up to two external temperature sensors.

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COMMUNICATIONS

The bq34z653 uses SMBus v1.1 with MASTER mode and packet error checking (PEC) options per the SBS specification.

SMBus On and Off State

The bq34z653 detects an SMBus off state when SMBC and SMBD are logic-low for \geq 2 s. Clearing this state requires either SMBC or SMBD to transition high. Within 1 ms, the communication bus is available.

SBS Commands

Table 2. SBS COMMANDS

| SBS | | | | Size in | Min | Max | | |
|------|------|------------------------|------------------|---------|---------|-------------|---------------|---------------|
| Cmd | Mode | Name | Format | Bytes | Value | Value | Default Value | Unit |
| 0x00 | R/W | ManufacturerAccess | Hex | 2 | 0x0000 | 0xffff | _ | |
| 0x01 | R/W | RemainingCapacityAlarm | Integer | 2 | 0 | 700 or 1000 | 300 or 432 | mAh or 10 mWh |
| 0x02 | R/W | RemainingTimeAlarm | Unsigned integer | 2 | 0 | 30 | 10 | min |
| 0x03 | R/W | BatteryMode | Hex | 2 | 0x0000 | 0xffff | _ | _ |
| 0x04 | R/W | AtRate | Integer | 2 | -32,768 | 32,767 | _ | mA or 10 mW |
| 0x05 | R | AtRateTimeToFull | Unsigned integer | 2 | 0 | 65,535 | _ | min |
| 0x06 | R | AtRateTimeToEmpty | Unsigned integer | 2 | 0 | 65,535 | _ | min |
| 0x07 | R | AtRateOK | Unsigned integer | 2 | 0 | 65,535 | _ | _ |
| 80x0 | R | Temperature | Unsigned integer | 2 | 0 | 65,535 | _ | 0.1°K |
| 0x09 | R | Voltage | Unsigned integer | 2 | 0 | 20,000 | _ | mV |
| 0x0a | R | Current | Integer | 2 | -32,768 | 32767 | _ | mA |
| 0x0b | R | AverageCurrent | Integer | 2 | -32,768 | 32,767 | _ | mA |
| 0x0c | R | MaxError | Unsigned integer | 1 | 0 | 100 | _ | % |
| 0x0d | R | RelativeStateOfCharge | Unsigned integer | 1 | 0 | 100 | _ | % |
| 0x0e | R | AbsoluteStateOfCharge | Unsigned integer | 1 | 0 | 100+ | _ | % |
| 0x0f | R/W | RemainingCapacity | Unsigned integer | 2 | 0 | 65,535 | _ | mAh or 10 mWh |
| 0x10 | R | FullChargeCapacity | Unsigned integer | 2 | 0 | 65,535 | _ | mAh or 10 mWh |
| 0x11 | R | RunTimeToEmpty | Unsigned integer | 2 | 0 | 65,534 | _ | min |
| 0x12 | R | AverageTimeToEmpty | Unsigned integer | 2 | 0 | 65,534 | _ | min |
| 0x13 | R | AverageTimeToFull | Unsigned integer | 2 | 0 | 65,534 | _ | min |
| 0x14 | R | ChargingCurrent | Unsigned integer | 2 | 0 | 65,534 | _ | mA |
| 0x15 | R | ChargingVoltage | Unsigned integer | 2 | 0 | 65,534 | _ | mV |
| 0x16 | R | BatteryStatus | Hex | 2 | 0x0000 | 0xdbff | | _ |
| 0x17 | R/W | CycleCount | Unsigned integer | 2 | 0 | 65,535 | 0 | |
| 0x18 | R/W | DesignCapacity | Integer | 2 | 0 | 32,767 | 4400 or 6336 | mAh or 10 mWh |
| 0x19 | R/W | DesignVoltage | Integer | 2 | 7000 | 18,000 | 14,400 | mV |





Table 2. SBS COMMANDS (continued)

| SBS Cmd | Mode | Name | Format | Size in Bytes | Min Value | Max Value | Default Value | Unit |
|------------|------|-------------------|------------------|------------------|--------------|--------------|----------------------|------|
| 0x1a | R/W | SpecificationInfo | Hex | 2 | 0x0000 | 0xffff | 0x0031 | _ |
| 0x1b | R/W | ManufactureDate | Unsigned integer | 2 | 0 | 65,535 | 0 | |
| 0x1c | R/W | SerialNumber | Hex | 2 | 0x0000 | 0xffff | 0x0000 | _ |
| 0x20 | R/W | ManufacturerName | String | 20+1 | _ | _ | Texas Instruments | |
| 0x21 | R/W | DeviceName | String | 20+1 | _ | _ | bq34z653 | _ |
| 0x22 | R/W | DeviceChemistry | String | 4+1 | _ | _ | LION | _ |
| 0x23 | R | ManufacturerData | String | 14+1 | _ | _ | _ | _ |
| 0x2f | R/W | Authenticate | String | 20+1 | _ | _ | _ | _ |
| 0x3c | R | CellVoltage4 | Unsigned integer | 2 | 0 | 65,535 | _ | mV |
| 0x3d | R | CellVoltage3 | Unsigned integer | 2 | 0 | 65,535 | _ | mV |
| 0x3e | R | CellVoltage2 | Unsigned integer | 2 | 0 | 65,535 | _ | mV |
| 0x3f | R | CellVoltage1 | Unsigned integer | 2 | 0 | 65,535 | _ | mV |

Table 3. EXTENDED SBS COMMANDS

| SBS Cmd | Mode | Name | Format | Size in Bytes | Min Value | Max Value | Default Value | Unit |
|---------|------|-----------------|------------------|------------------|------------|-----------|------------------|-------|
| 0x45 | R | AFEData | String | 11+1 | _ | _ | _ | _ |
| 0x46 | R/W | FETControl | Hex | 2 | 0x00 | 0xff | _ | _ |
| 0x4f | R | StateOfHealth | Hex | 2 | 0x0000 | 0xffff | _ | % |
| 0x51 | R | SafetyStatus | Hex | 2 | 0x0000 | 0xffff | _ | _ |
| 0x52 | R | PFAlert | Hex | 2 | 0x0000 | 0xffff | _ | _ |
| 0x53 | R | PFStatus | Hex | 2 | 0x0000 | 0xffff | _ | _ |
| 0x54 | R | OperationStatus | Hex | 2 | 0x0000 | 0xffff | _ | _ |
| 0x55 | R | ChargingStatus | Hex | 2 | 0x0000 | 0xffff | _ | _ |
| 0x57 | R | ResetData | Hex | 2 | 0x0000 | 0xffff | _ | _ |
| 0x58 | R | WDResetData | Unsigned integer | 2 | 0 | 65,535 | _ | _ |
| 0x5a | R | PackVoltage | Unsigned integer | 2 | 0 | 65,535 | _ | mV |
| 0x5d | R | AverageVoltage | Unsigned integer | 2 | 0 | 65,535 | _ | mV |
| 0x5e | R | TS1Temperature | Integer | 2 | -400 | 1200 | _ | 0.1°C |
| 0x5f | R | TS2Temperature | Integer | 2 | -400 | 1200 | _ | 0.1°C |
| 0x60 | R/W | UnSealKey | Hex | 4 | 0x00000000 | 0xfffffff | _ | _ |
| 0x61 | R/W | FullAccessKey | Hex | 4 | 0x00000000 | 0xfffffff | _ | _ |
| 0x62 | R/W | PFKey | Hex | 4 | 0x00000000 | 0xfffffff | _ | _ |
| 0x63 | R/W | AuthenKey3 | Hex | 4 | 0x00000000 | 0xfffffff | _ | _ |
| 0x64 | R/W | AuthenKey2 | Hex | 4 | 0x00000000 | 0xfffffff | _ | _ |
| 0x65 | R/W | AuthenKey1 | Hex | 4 | 0x00000000 | 0xfffffff | _ | _ |
| 0x66 | R/W | AuthenKey0 | Hex | 4 | 0x00000000 | 0xfffffff | _ | _ |
| 0x68 | R | SafetyAlert2 | Hex | 2 | 0x0000 | 0x000f | _ | _ |
| 0x69 | R | SafetyStatus2 | Hex | 2 | 0x0000 | 0x000f | _ | _ |
| 0x6a | R | PFAlert2 | Hex | 2 | 0x0000 | 0x000f | _ | _ |
| 0x6b | R | PFStatus2 | Hex | 2 | 0x0000 | 0x000f | _ | _ |

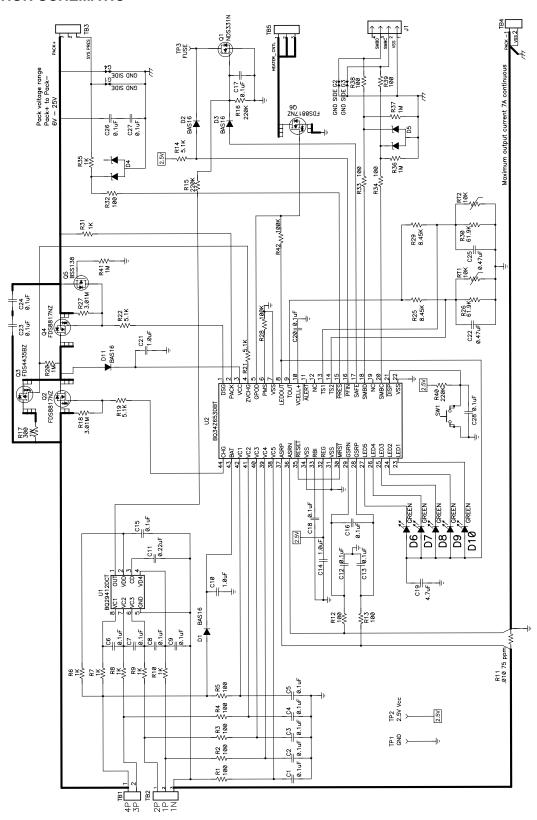
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Table 3. EXTENDED SBS COMMANDS (continued)

| SBS Cmd | Mode | Name | Format | Size in Bytes | Min Value | Max Value | Default Value | Unit |
|---------|------|------------------------|------------------|------------------|-----------|-----------|------------------|------|
| 0x6c | R | ManufBlock1 | String | 20 | _ | _ | _ | _ |
| 0x6d | R | ManufBlock2 | String | 20 | _ | _ | _ | _ |
| 0x6e | R | ManufBlock3 | String | 20 | _ | _ | _ | _ |
| 0x6f | R | ManufBlock4 | String | 20 | _ | _ | _ | _ |
| 0x70 | R/W | ManufacturerInfo | String | 31+1 | _ | _ | _ | _ |
| 0x71 | R/W | SenseResistor | Unsigned integer | 2 | 0 | 65,535 | _ | μΩ |
| 0x72 | R | TempRange | Hex | 2 | _ | _ | _ | _ |
| 0x73 | R | LifetimeData1 | String | 32+1 | _ | _ | _ | _ |
| 0x74 | R | LifetimeData2 | String | 8+1 | _ | _ | _ | _ |
| 0x77 | R/W | DataFlashSubClassID | Hex | 2 | 0x0000 | 0xffff | _ | _ |
| 0x78 | R/W | DataFlashSubClassPage1 | Hex | 32 | _ | _ | _ | _ |
| 0x79 | R/W | DataFlashSubClassPage2 | Hex | 32 | _ | _ | _ | _ |
| 0x7a | R/W | DataFlashSubClassPage3 | Hex | 32 | _ | _ | _ | _ |
| 0x7b | R/W | DataFlashSubClassPage4 | Hex | 32 | _ | _ | _ | _ |
| 0x7c | R/W | DataFlashSubClassPage5 | Hex | 32 | _ | _ | _ | _ |
| 0x7d | R/W | DataFlashSubClassPage6 | Hex | 32 | _ | _ | _ | _ |
| 0x7e | R/W | DataFlashSubClassPage7 | Hex | 32 | _ | _ | _ | _ |
| 0x7f | R/W | DataFlashSubClassPage8 | Hex | 32 | _ | _ | _ | _ |



APPLICATION SCHEMATIC







20-Sep-2012

PACKAGING INFORMATION

| Orderable Device | Status (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan ⁽²⁾ | Lead/ Ball Finish | MSL Peak Temp ⁽³⁾ | Samples (Requires Login) |
|------------------|------------|--------------|--------------------|------|-------------|----------------------------|----------------------|------------------------------|-----------------------------|
| BQ34Z653DBT | ACTIVE | TSSOP | DBT | 44 | 40 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-2-250C-1 YEAR | |
| BQ34Z653DBTR | ACTIVE | TSSOP | DBT | 44 | 2000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-2-260C-1 YEAR | |

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





| _ | | |
|---|----|---|
| | | Dimension designed to accommodate the component width |
| | B0 | Dimension designed to accommodate the component length |
| | K0 | Dimension designed to accommodate the component thickness |
| | W | Overall width of the carrier tape |
| ı | P1 | Pitch between successive cavity centers |

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

| Device | Package Type | Package Drawing | | | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|--------------|-----------------|--------------------|----|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| BQ34Z653DBTR | TSSOP | DBT | 44 | 2000 | 330.0 | 24.4 | 6.8 | 11.7 | 1.6 | 12.0 | 24.0 | Q1 |

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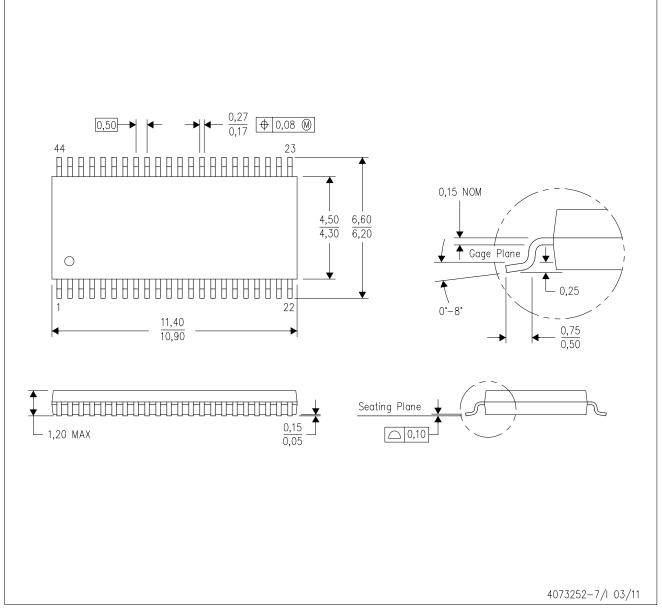


*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|--------------|--------------|-----------------|------|------|-------------|------------|-------------|
| BQ34Z653DBTR | TSSOP | DBT | 44 | 2000 | 367.0 | 367.0 | 45.0 |

DBT (R-PDSO-G44)

PLASTIC SMALL OUTLINE



All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994. This drawing is subject to change without notice. NOTES:

C. Body dimensions do not include mold flash or protrusion.



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